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Dual non-inverting Schmitt trigger Rev. 01 — 6 October 2006

Product data sheet

General description 1.

The 74HC2G17; 74HCT2G17 is a high-speed Si-gate CMOS device.

The 74HC2G17; 74HCT2G17 provides two non-inverting Schmitt trigger buffers. They are capable of transforming slowly changing input signals into sharply defined, jitter-free output signals.

The inputs switch at different points for positive and negative-going signals. The difference between the positive voltage $V_{T_{+}}$ and the negative voltage $V_{T_{-}}$ is defined as the input hysteresis voltage V_H.

2. **Features**

- Wide supply voltage range from 2.0 V to 6.0 V
- Complies with JEDEC standard no. 7A
- High noise immunity
- ESD protection:
 - HBM JESD22-A114-D exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- Low power dissipation
- Balanced propagation delays
- Unlimited input rise and fall times
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

3. Applications

- Wave and pulse shaper for highly noisy environments
- Astable multivibrators
- Monostable multivibrators



Dual non-inverting Schmitt trigger

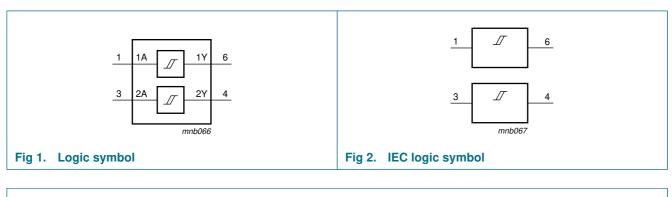
4. Ordering information

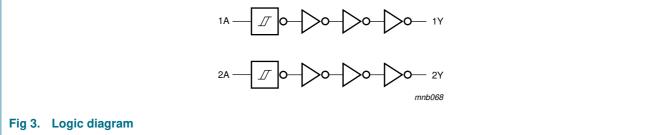
Table 1. Ordering information									
Type number	Package								
	Temperature range	Name	Description	Version					
74HC2G17GW	–40 °C to +125 °C	SC-88	plastic surface-mounted package; 6 leads	SOT363					
74HC2G17GV	–40 °C to +125 °C	SC-74	plastic surface-mounted package (TSOP6); 6 leads	SOT457					
74HCT2G17GW	–40 °C to +125 °C	SC-88	plastic surface-mounted package; 6 leads	SOT363					
74HCT2G17GV	–40 °C to +125 °C	SC-74	plastic surface-mounted package (TSOP6); 6 leads	SOT457					

5. Marking

Table 2. Marking	
Type number	Marking code
74HC2G17GW	HV
74HC2G17GV	HV
74HCT2G17GW	TV
74HCT2G17GV	TV

6. Functional diagram

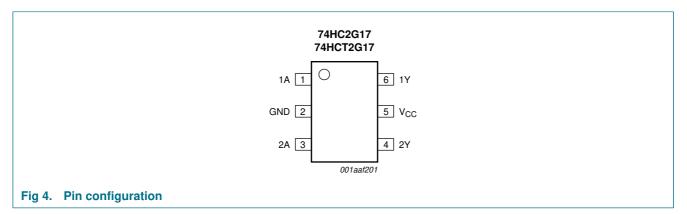




Dual non-inverting Schmitt trigger

7. Pinning information

7.1 Pinning



7.2 Pin description

Table 3.	Pin description	
Symbol	Pin	Description
1A	1	data input
GND	2	ground (0 V)
2A	3	data input
2Y	4	data output
V _{CC}	5	supply voltage
1Y	6	data output

8. Functional description

Table 4. Function table^[1]

Input	Output
	nY
L	L
Н	Н

[1] H = HIGH voltage level;

L = LOW voltage level.

Dual non-inverting Schmitt trigger

9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7.0	V
I _{IK}	input clamping current	$V_{\rm I} < -0.5$ V or $V_{\rm I} > V_{\rm CC}$ + 0.5 V	<u>[1]</u> _	±20	mA
I _{OK}	output clamping current	$V_O < -0.5$ V or $V_O > V_{CC}$ + 0.5 V	<u>[1]</u> _	±20	mA
lo	output current	V_{O} = -0.5 V to V_{CC} + 0.5 V	<u>[1]</u> _	±25	mA
I _{CC}	supply current		<u>[1]</u> _	50	mA
I _{GND}	ground current		<u>[1]</u> _	-50	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation		[2] _	250	mW

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SC-88 and SC-74 packages: above 87.5 °C the value of Ptot derates linearly with 4.0 mW/K.

10. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Type 74HC	2G17					
V _{CC}	supply voltage		2.0	5.0	6.0	V
VI	input voltage		0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	°C
Type 74HC	T2G17					
V _{CC}	supply voltage		4.5	5.0	5.5	V
VI	input voltage		0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	°C

11. Static characteristics

Table 7. Static characteristics for 74HC2G17

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 25	°C					
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_O = –20 $\mu\text{A};V_{CC}$ = 2.0 V	1.9	2.0	-	V
		I_O = –20 $\mu\text{A};V_{CC}$ = 4.5 V	4.4	4.5	-	V
		$I_{O} = -20 \ \mu A; \ V_{CC} = 6.0 \ V$	5.9	6.0	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	4.18	4.32	-	V
		$I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.68	5.81	-	V

74HC_HCT2G17_1
Product data sheet

Dual non-inverting Schmitt trigger

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_{O} = 20 \ \mu A; V_{CC} = 2.0 \ V$	-	0	0.1	V
		$I_{O} = 20 \ \mu A; V_{CC} = 4.5 \ V$	-	0	0.1	V
		$I_{O} = 20 \ \mu A; V_{CC} = 6.0 \ V$	-	0	0.1	V
		$I_{O} = 4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.26	V
		$I_{O} = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	V
I _I	input leakage current	$V_I = GND \text{ or } V_{CC}; V_{CC} = 6.0 \text{ V}$	-	-	±0.1	μA
I _{CC}	supply current	$\label{eq:V_l} \begin{array}{l} V_{I} = GND \text{ or } V_{CC}; \ I_{O} = 0 \ A; \\ V_{CC} = 6.0 \ V \end{array}$	-	-	1.0	μA
Cı	input capacitance		-	2.0	-	pF
T _{amb} = -40) °C to +85 °C					
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_{O} = -20 \ \mu A; \ V_{CC} = 2.0 \ V$	1.9	-	-	V
		$I_{O} = -20 \ \mu A; \ V_{CC} = 4.5 \ V$	4.4	-	-	V
		$I_{O} = -20 \ \mu A; \ V_{CC} = 6.0 \ V$	5.9	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	4.13	-	-	V
		$I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.63	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{IH} \text{ or } V_{IL}$				
		$I_{O} = 20 \ \mu A; \ V_{CC} = 2.0 \ V$	-	-	0.1	V
		$I_{O} = 20 \ \mu A; \ V_{CC} = 4.5 \ V$	-	-	0.1	V
		$I_{O} = 20 \ \mu A; \ V_{CC} = 6.0 \ V$	-	-	0.1	V
		$I_{O} = 4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.33	V
		$I_{O} = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	-	0.33	V
lı	input leakage current	$V_I = GND \text{ or } V_{CC}; V_{CC} = 6.0 \text{ V}$	-	-	±1.0	μA
I _{CC}	supply current	$\label{eq:VI} \begin{array}{l} V_{I} = GND \text{ or } V_{CC}; \ I_{O} = 0 \ A; \\ V_{CC} = 6.0 \ V \end{array}$	-	-	10.0	μA
T _{amb} = -40) °C to +125 °C					
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_{O} = -20 \ \mu A; \ V_{CC} = 2.0 \ V$	1.9	-	-	V
		$I_{O} = -20 \ \mu A; \ V_{CC} = 4.5 \ V$	4.4	-	-	V
		$I_{O} = -20 \ \mu A; \ V_{CC} = 6.0 \ V$	5.9	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.7	-	-	V
		$I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.2	-	-	V

Table 7. Static characteristics for 74HC2G17 ... continued

Dual non-inverting Schmitt trigger

Table 7. Static characteristics for 74HC2G17 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_{O} = 20 \ \mu A; \ V_{CC} = 2.0 \ V$	-	-	0.1	V
		$I_{O} = 20 \ \mu A; \ V_{CC} = 4.5 \ V$	-	-	0.1	V
		$I_{O} = 20 \ \mu A; \ V_{CC} = 6.0 \ V$	-	-	0.1	V
		$I_{O} = 4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.4	V
		$I_{O} = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	-	0.4	V
I _I	input leakage current	$V_I = GND \text{ or } V_{CC}; V_{CC} = 6.0 \text{ V}$	-	-	±1.0	μA
I _{CC}	supply current	$V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ $V_{CC} = 6.0 \text{ V}$	-	-	20.0	μA

Table 8. Static characteristics for 74HCT2G17

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T_{amb} = 25 °	С					
V _{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 V$				
		$I_O = -20 \ \mu A$	4.4	4.5	-	V
		$I_{O} = -4.0 \text{ mA}$	4.18	4.32	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
		I _O = -20 μA	-	0	0.1	V
		$I_{O} = -4.0 \text{ mA}$	-	0.15	0.26	V
lı	input leakage current	$V_I = GND \text{ or } V_{CC}; V_{CC} = 5.5 \text{ V}$	-	-	±0.1	μA
I _{CC}	supply current	$\label{eq:VI} \begin{array}{l} V_{I} = GND \text{ or } V_{CC}; \ I_{O} = 0 \ A; \\ V_{CC} = 5.5 \ V \end{array}$	-	-	1.0	μA
ΔI_{CC}	additional supply current	$V_{I} = V_{CC} - 2.1 \text{ V};$ $V_{CC} = 4.5 \text{ V}$ to 5.5 V; $I_{O} = 0 \text{ A}$	-	-	300	μA
CI	input capacitance		-	2.0	-	pF
$T_{amb} = -40$	°C to +85 °C					
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
		I _O = -20 μA	4.4	-	-	V
		$I_{O} = -4.0 \text{ mA}$	4.13	-	-	V
V _{OL}	LOW-level output voltage	V_{I} = V_{IH} or $V_{IL};V_{CC}$ = 4.5 V				
		I _O = -20 μA	-	-	0.1	V
		$I_{O} = -4.0 \text{ mA}$	-	-	0.33	V
l _l	input leakage current	$V_I = GND \text{ or } V_{CC}; V_{CC} = 5.5 \text{ V}$	-	-	±1.0	μA
Icc	supply current	$\label{eq:VI} \begin{array}{l} V_{I} = GND \text{ or } V_{CC}; \ I_{O} = 0 \ A; \\ V_{CC} = 5.5 \ V \end{array}$	-	-	10.0	μA
ΔI_{CC}	additional supply current	$V_{I} = V_{CC} - 2.1 \text{ V};$ $V_{CC} = 4.5 \text{ V}$ to 5.5 V; $I_{O} = 0 \text{ A}$	-	-	375	μA

Dual non-inverting Schmitt trigger

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -40	°C to +125 °C					
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 V$				
		$I_{O} = -20 \ \mu A$	4.4	-	-	V
		$I_{O} = -4.0 \text{ mA}$	3.7	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 V$				
		$I_{O} = -20 \ \mu A$	-	-	0.1	V
		$I_{O} = -4.0 \text{ mA}$	-	-	0.4	V
l _l	input leakage current	$V_{I} = GND \text{ or } V_{CC}; V_{CC} = 5.5 \text{ V}$	-	-	±1.0	μA
I _{CC}	supply current	$V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ $V_{CC} = 5.5 \text{ V}$	-	-	20.0	μA
ΔI_{CC}	additional supply current	$V_{I} = V_{CC} - 2.1 V;$ $V_{CC} = 4.5 V$ to 5.5 V; $I_{O} = 0 A$	-	-	410	μA

Table 8. Static characteristics for 74HCT2G17 ... continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

12. Dynamic characteristics

Dynamic characteristics Table 9.

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 6.

Symbol	Parameter	Conditions			25 °C		-4	0 °C to +1	25 °C	Unit
				Min	Тур	Max	Min	Мах (85 °С)	Max (125 °C)	
74HC2G1	7									
t _{pd}	propagation delay	nA to nY; see Figure 5	[1]							
		$V_{CC} = 2.0 \text{ V}; C_L = 50 \text{ pF}$		-	36	115	-	140	175	ns
		$V_{CC} = 4.5 \text{ V}; C_L = 50 \text{ pF}$		-	12	22	-	27	34	ns
		$V_{CC} = 6.0 \text{ V}; C_L = 50 \text{ pF}$		-	10	18	-	22	28	ns
t _t	transition time	nY; see <u>Figure 5</u>	[2]							
		$V_{CC} = 2.0 \text{ V}; C_L = 50 \text{ pF}$		-	20	75	-	95	110	ns
		$V_{CC} = 4.5 \text{ V}; C_L = 50 \text{ pF}$		-	7	15	-	19	22	ns
		$V_{CC} = 6.0 \text{ V}; C_L = 50 \text{ pF}$		-	5	13	-	16	19	ns
C _{PD}	power dissipation capacitance	$V_I = GND$ to V_{CC}	[3]	-	10	-	-	-	-	pF

Dual non-inverting Schmitt trigger

Symbol	Parameter	Conditions		25 °C		–40 °C to +125 °C			Unit	
				Min	Тур	Max	Min	Max (85 °C)	Max (125 °C)	
74HCT26	17									
t _{pd} p	propagation delay	nA to nY; see Figure 5	<u>[1]</u>							
		$V_{CC} = 4.5 \text{ V}; \text{ C}_{L} = 50 \text{ pF}$		-	21	29	-	36	45	ns
t _t	transition time	nY; see <u>Figure 5</u>	[2]							
		$V_{CC} = 4.5 \text{ V}; \text{ C}_{L} = 50 \text{ pF}$		-	6	15	-	19	22	ns
C _{PD}	power dissipation capacitance	$V_{I}=GND$ to $V_{CC}-1.5~V$	[3]	-	10	-	-	-	-	pF

Dynamic characteristics ... continued Table 9.

-----010.6

[1] t_{pd} is the same as t_{PLH} and t_{PHL}

- [2] t_t is the same as t_{TLH} and t_{THL}
- [3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

 f_0 = output frequency in MHz;

C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

13. Waveforms

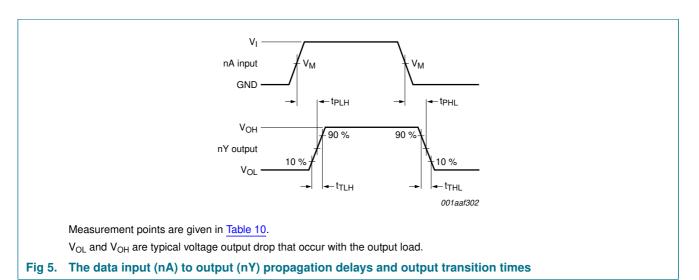


Table 10. Measurement points

Туре	Input	Output		
	V _M	VI	t _r = t _f	V _M
74HC2G17	0.5V _{CC}	GND to V _{CC}	6.0 ns	0.5V _{CC}
74HCT2G17	1.3 V	GND to 3.0 V	6.0 ns	1.3 V

74HC_HCT2G17_1 Product data sheet

74HC2G17; 74HCT2G17

Dual non-inverting Schmitt trigger

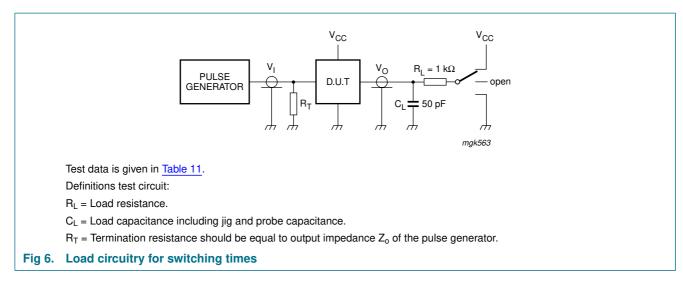


Table 11. Test data

Туре	Input	Test	
	VI	t _r , t _f	t _{PHL} , t _{PLH}
74HC2G17	GND to V _{CC}	6 ns	open
74HCT2G17	GND to 3.0 V	6 ns	open

14. Transfer characteristics

Table 12. Transfer characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 6.

Symbol	Parameter	Conditions		25 °C		–40 °C to +125 °C			Unit
			Min	Тур	Max	Min	Max (85 °C)	Max (125 °C)	
74HC2G	17								
V_{T+}	positive-going	see Figure 7, Figure 8							
	threshold voltage	$V_{CC} = 2.0 V$	1.00	1.18	1.50	1.00	1.50	1.50	V
		$V_{CC} = 4.5 V$	2.30	2.60	3.15	2.30	3.15	3.15	V
		$V_{CC} = 6.0 V$	3.00	3.46	4.20	3.00	4.20	4.20	V
V _{T-}	negative-going threshold voltage	see Figure 7, Figure 8							
		$V_{CC} = 2.0 V$	0.30	0.60	0.90	0.30	0.90	0.90	V
		$V_{CC} = 4.5 V$	1.13	1.47	2.00	1.13	2.00	2.00	V
		$V_{CC} = 6.0 V$	1.50	2.06	2.60	1.50	2.60	2.60	V
V _H	hysteresis voltage	V _{T+} – V _{T–} ; see <u>Figure 7,</u> <u>Figure 8</u> and <u>Figure 9</u>							
		$V_{CC} = 2.0 V$	0.30	0.60	1.00	0.30	1.00	1.00	V
		$V_{CC} = 4.5 V$	0.60	1.13	1.40	0.60	1.40	1.40	V
		$V_{CC} = 6.0 V$	0.80	1.40	1.70	0.80	1.70	1.70	V

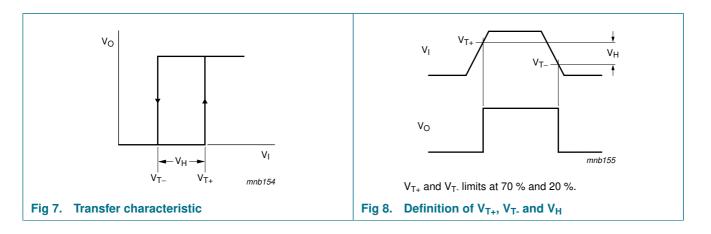
Dual non-inverting Schmitt trigger

Symbol	Parameter	Conditions		25 °C			–40 °C to +125 °C		
			Min	Тур	Max	Min	Max (85 °C)	Max (125 °C)	-
74HCT2	G17								
V _{T+} positive-going		see Figure 7 and Figure 8							
	threshold voltage	$V_{CC} = 4.5 V$	1.20	1.58	1.90	1.20	1.90	1.90	V
		$V_{CC} = 5.5 V$	1.40	1.78	2.10	1.40	2.10	2.10	V
V _{T-}	negative-going threshold voltage	see Figure 7 and Figure 8							
		$V_{CC} = 4.5 V$	0.50	0.87	1.20	0.50	1.20	1.20	V
		$V_{CC} = 5.5 V$	0.60	1.11	1.40	0.60	1.40	1.40	V
V _H	hysteresis voltage	V _{T+} – V _{T-} ; see <u>Figure 7,</u> <u>Figure 8</u> and <u>Figure 10</u>							
		$V_{CC} = 4.5 V$	0.40	0.71	-	0.40	-	-	V
		$V_{CC} = 5.5 V$	0.40	0.67	-	0.40	-	-	V

Table 12. Transfer characteristics ...continued

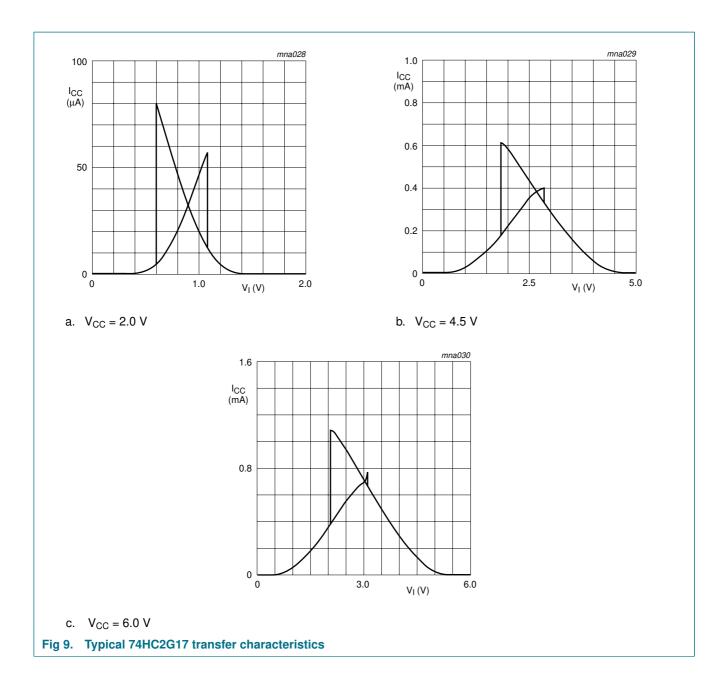
Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 6.

15. Waveforms transfer characteristics



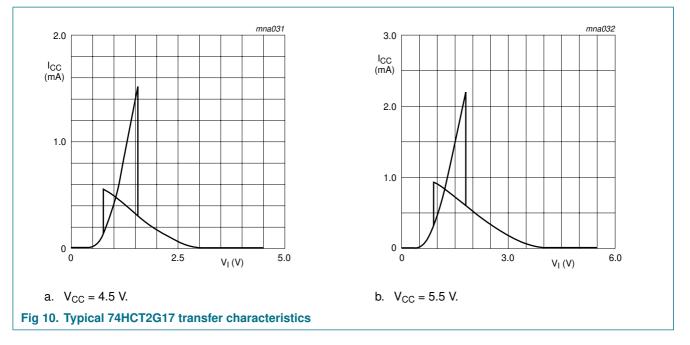
74HC2G17; 74HCT2G17

Dual non-inverting Schmitt trigger



74HC2G17; 74HCT2G17

Dual non-inverting Schmitt trigger



16. Application information

The slow input rise and fall times cause additional power dissipation, this can be calculated using the following formula:

 $P_{add} = f_i \times (t_r \times \Delta I_{CC(AV)} + t_f \times \Delta I_{CC(AV)}) \times V_{CC}$ where:

 P_{add} = additional power dissipation (μ W);

 $f_i = input frequency (MHz);$

 t_r = input rise time (ns); 10 % to 90 %;

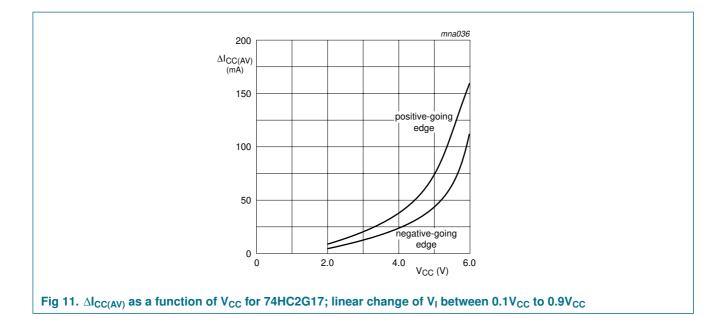
 t_f = input fall time (ns); 90 % to 10 %;

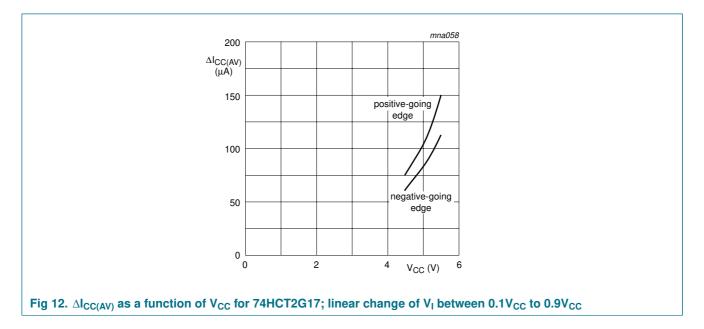
 $\Delta I_{CC(AV)}$ = average additional supply current (µA).

 $\Delta I_{CC(AV)}$ differs with positive or negative input transitions, as shown in Figure 11 and Figure 12.

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17. Package outline

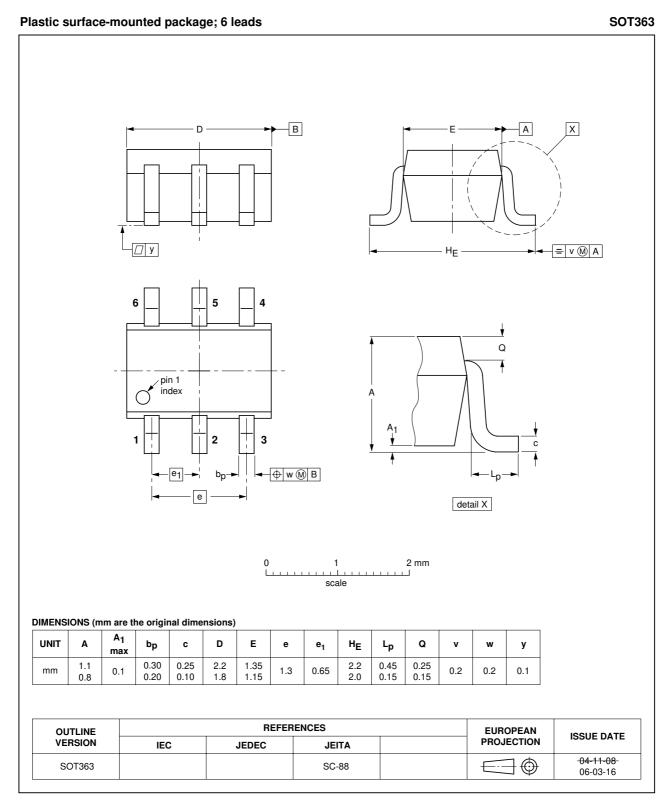
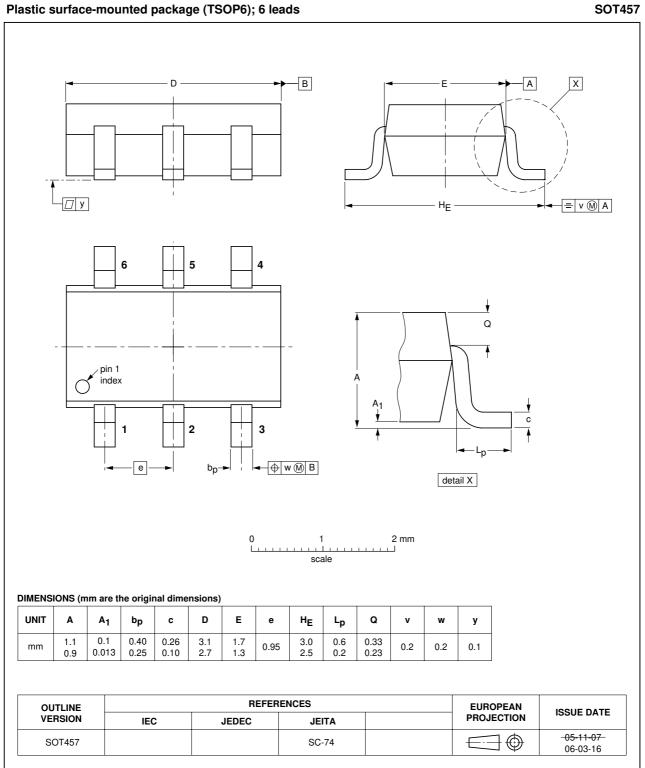


Fig 13. Package outline SOT363 (SC-88)

Dual non-inverting Schmitt trigger



Plastic surface-mounted package (TSOP6); 6 leads

Fig 14. Package outline SOT457 (SC-74)



Dual non-inverting Schmitt trigger

18. Abbreviations

Table 13. Abbreviations				
Acronym	Description			
CMOS	Complementary Metal Oxide Semiconductor			
ESD	ElectroStatic Discharge			
HBM	Human Body Model			
MM	Machine Model			
DUT	Device Under Test			

19. Revision history

Table 14. Revision history						
Document ID	Release date	Data sheet status	Change notice	Supersedes		
74HC_HCT2G17_1	20061006	Product data sheet	-	-		

Dual non-inverting Schmitt trigger

20. Legal information

20.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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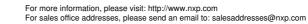
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